

RGTH60TK65

650V 30A Field Stop Trench IGBT

V _{CES}	650V
I _{C(100°C)}	17A
V _{CE(sat) (Typ.)}	1.6V@I _C =30A
P_D	61W

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

Applications

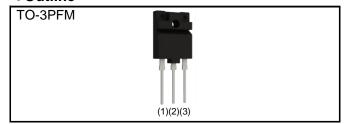
PFC

UPS

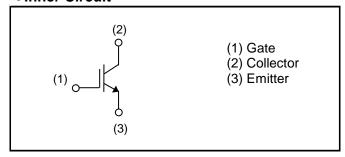
Power Conditioner

ΙH

Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube		
	Reel Size (mm)	-		
Tuno	Tape Width (mm)	-		
Туре	Basic Ordering Unit (pcs)	450		
	Packing Code C1			
	Marking	RGTH60TK65		

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V_{CES}	650	V
Gate - Emitter Voltage		V_{GES}	±30	V
Collector Current	T _C = 25°C	I _C	28	А
Collector Current	T _C = 100°C	= 100°C I _C 17		А
Pulsed Collector Current		I _{CP} *1	120	А
$T_C = 25^{\circ}C$		P_{D}	61	W
Power Dissipation $T_C = 100^{\circ}C$		P _D	30	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by T_{jmax.}

●Thermal Resistance

Parameter	Symbol	Values			Unit
raiametei	Symbol	Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	2.43	°C/W

ullet IGBT Electrical Characteristics (at $T_j = 25$ °C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
raiainetei	Syllibol	Conditions	Min.	Тур.	Max.	Offic
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	ı	1	V
Collector Cut - off Current	I _{CES}	$V_{CE} = 650V, V_{GE} = 0V$	1	1	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V$, $V_{CE} = 0V$		-	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$V_{CE} = 5V, I_{C} = 21.0 \text{mA}$	4.5	5.5	6.5	V
Collector - Emitter Saturation Voltage	V _{CE(sat)}	$I_C = 30A$, $V_{GE} = 15V$ $T_j = 25$ °C $T_j = 175$ °C	-	1.6 2.1	2.1 -	V

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Dorometer	Symbol	Conditions	Values			Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input Capacitance	C _{ies}	V _{CE} = 30V	-	1670	-	
Output Capacitance	C _{oes}	$V_{GE} = 0V$	-	66	-	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	27	-	
Total Gate Charge	Q_g	V _{CE} = 300V	-	58	-	
Gate - Emitter Charge	Q_ge	I _C = 30A	-	15	-	nC
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	20	-	
Turn - on Delay Time	t _{d(on)}	$I_C = 30A, V_{CC} = 400V$	-	27	-	
Rise Time	t _r	$V_{GE} = 15V, R_G = 10\Omega$	-	40	-	
Turn - off Delay Time	t _{d(off)}	T _j = 25°C	-	105	-	ns
Fall Time	t _f	Inductive Load	-	47	-	
Turn - on Delay Time	t _{d(on)}	$I_C = 30A, V_{CC} = 400V$	-	27	-	
Rise Time	t _r	$V_{GE} = 15V, R_G = 10\Omega$	-	40	-	
Turn - off Delay Time	$t_{d(off)}$	T _j = 175°C	-	120	-	ns
Fall Time	t _f	Inductive Load	-	59	-	
		I _C = 120A, V _{CC} = 520V		-	-	
Reverse Bias Safe Operating Area	RBSOA	$V_P = 650 \text{V}, V_{GE} = 15 \text{V}$	FU	LL SQUA	RE	-
		$R_G = 60\Omega, T_j = 175^{\circ}C$				

Fig.1 Power Dissipation vs. Case Temperature

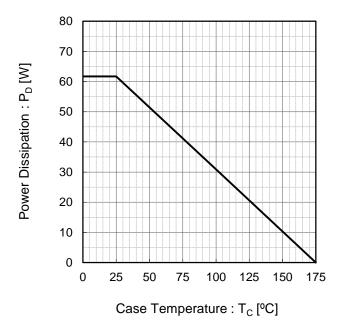


Fig.2 Collector Current vs. Case Temperature

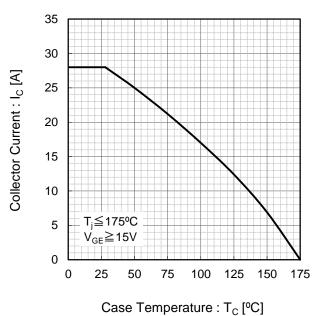


Fig.3 Forward Bias Safe Operating Area

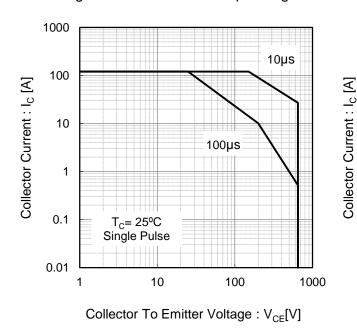
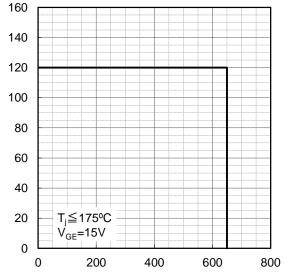


Fig.4 Reverse Bias Safe Operating Area



Collector To Emitter Voltage : $V_{CE}[V]$

Fig.5 Typical Output Characteristics

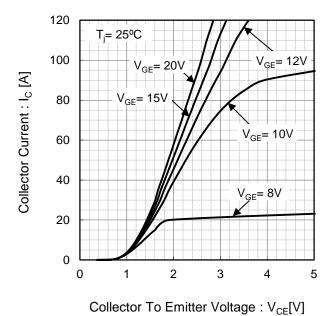
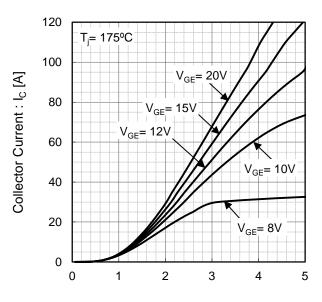


Fig.6 Typical Output Characteristics



Collector To Emitter Voltage : V_{CE}[V]

Fig.7 Typical Transfer Characteristics

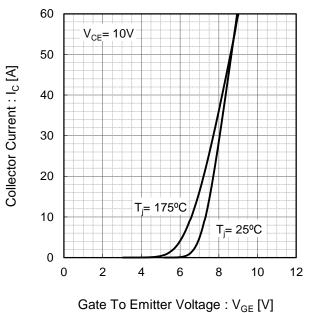
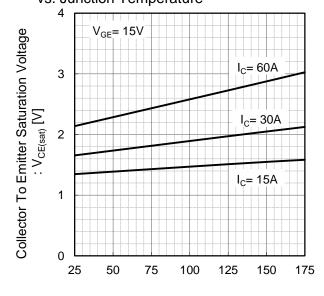
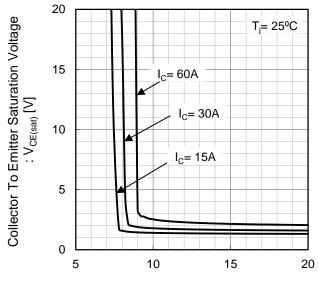


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



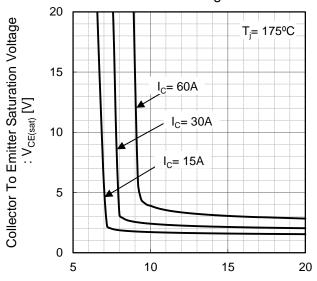
Junction Temperature : T_i [°C]

Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate To Emitter Voltage : V_{GE} [V]

Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate To Emitter Voltage: V_{GE} [V]

Fig.11 Typical Switching Time vs. Collector Current

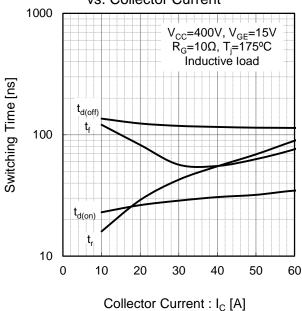


Fig.12 Typical Switching Time vs. Gate Resistance

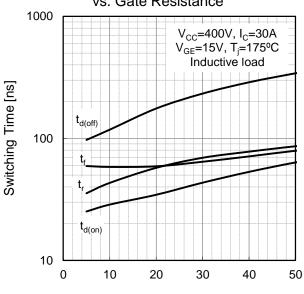


Fig.13 Typical Switching Energy Losses vs. Collector Current 10 Switching Energy Losses [mJ] 1 0.1 $V_{\rm CC}$ =400V, $V_{\rm GE}$ =15V R_G=10 Ω , T_j=175°C Inductive load 0.01 0 40 50 10 20 30 60 Collector Current : I_C [A]

vs. Gate Resistance

10

See Section 1

Eoff $V_{cc} = 400V, I_{c} = 30A$ $V_{GE} = 15V, T_{J} = 175^{\circ}C$ Inductive load $V_{cc} = 400V, I_{c} = 30A$ $V_{GE} = 15V, T_{J} = 175^{\circ}C$ $V_{CC} = 400V, I_{C} = 30A$ $V_{GE} = 15V, T_{J} = 175^{\circ}C$ $V_{CC} = 400V, I_{C} = 30A$ $V_{CC} = 40V, I_{C} = 30A$

Fig.14 Typical Switching Energy Losses

Fig.15 Typical Capacitance vs. Collector To Emitter Voltage 10000 Cies 1000 Capacitance [pF] Coes 100 Cres 10 f=1MHz $V_{GE}=0V$ T_i=25°C 0.01 0.1 1 10 100 Collector To Emitter Voltage : V_{CE}[V]

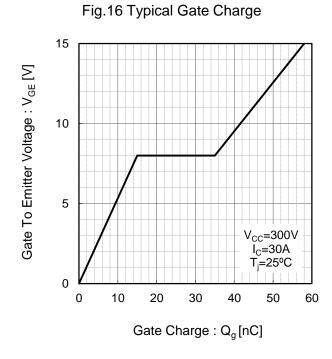
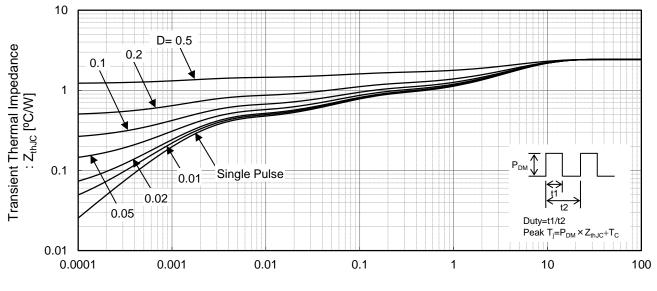


Fig.17 IGBT Transient Thermal Impedance



●Inductive Load Switching Circuit and Waveform

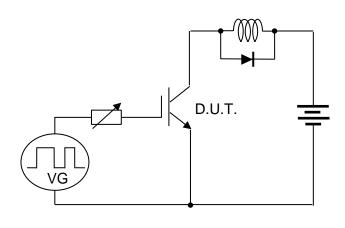


Fig.18 Inductive Load Circuit

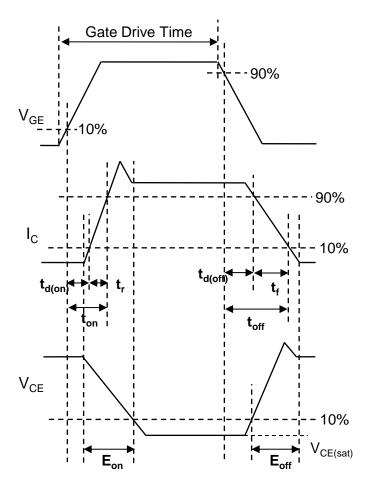


Fig.19 Inductive Load Waveform

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RGTH60TK65 - Web Page

Distribution Inventory

Part Number	RGTH60TK65
Package	TO-3PFM
Unit Quantity	450
Minimum Package Quantity	450
Packing Type	Tube
Constitution Materials List	inquiry
RoHS	Yes